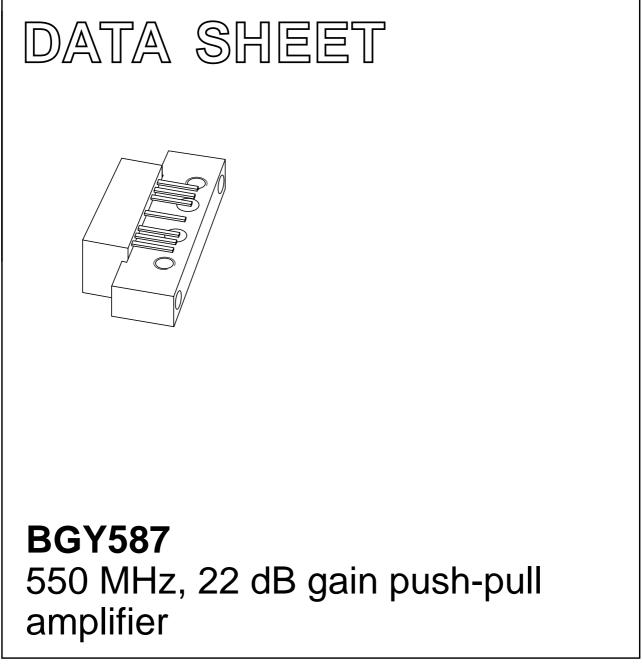
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1994 Feb 07

2001 Nov 27



FEATURES

Excellent linearity

- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

APPLICATIONS

• CATV systems operating in the 40 to 550 MHz frequency range.

DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC). The BGY587 is intended for use as a final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION	
1	input	
2, 3	common	
5	+V _B	
7, 8	common	
9	output	

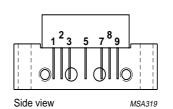


Fig.1 Simplified outline.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	21.5	_	22.5	dB
		f = 550 MHz	22	_	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	220	240	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY587

BGY587

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_S = Z_L = 75 $\Omega.$

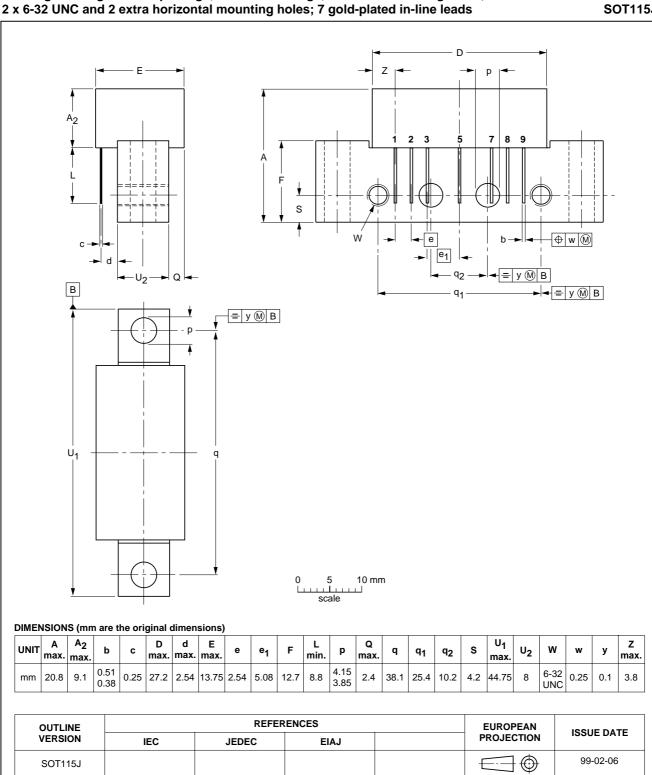
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	21.5	-	22.5	dB
		f = 550 MHz	22	-	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	-	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	-	±0.2	dB
s ₁₁	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 550 MHz	18	-	-	dB
\$ ₂₂	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 550 MHz	18	-	-	dB
s ₂₁	phase response	f = 50 MHz	+135	-	+225	deg
СТВ	composite triple beat	77 channels flat; $V_o = 44 \text{ dBmV}$; measured at 547.25 MHz	-	-	-57	dB
X _{mod}	cross modulation	77 channels flat; $V_o = 44 \text{ dBmV}$; measured at 55.25 MHz	-	-	-58	dB
CSO	composite second order distortion	77 channels flat; $V_o = 44 \text{ dBmV}$; measured at 548.5 MHz	-	-	-54	dB
d ₂	second order distortion	note 1	_	_	-66	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	-	-	dBmV
NF	noise figure	f = 550 MHz	-	-	7	dB
I _{tot}	total current consumption (DC)	note 3	-	220	240	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$ $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 548.5 \text{ MHz}.$
- 2. Measured according to DIN45004B: $f_p = 540.25 \text{ MHz}; V_p = V_0;$ $f_q = 547.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$ $f_r = 549.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at $f_p + f_q - f_r = 538.25 \text{ MHz}.$
- 3. The module normally operate at V_B = 24 V, but is able to withstand supply transients up to 30 V.

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes;

PACKAGE OUTLINE



BGY587

SOT115J

BGY587

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A, and SNW-FQ-302B.

NOTES

BGY587

BGY587

550 MHz, 22 dB gain push-pull amplifier

NOTES

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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